# Old Company Name in Catalogs and Other Documents

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# **3SK298** Silicon N-Channel Dual Gate MOS FET

REJ03G0817-0300 (Previous ADE-208-390A) Rev.3.00 Aug.10.2005

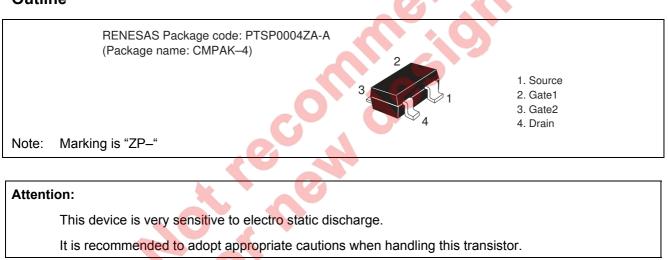
## Application

UHF / VHF RF amplifier

### Features

- Low noise figure. NF = 1.0 dB typ. at f = 200 MHz
- Capable of low voltage operation

### Outline





# Absolute Maximum Ratings

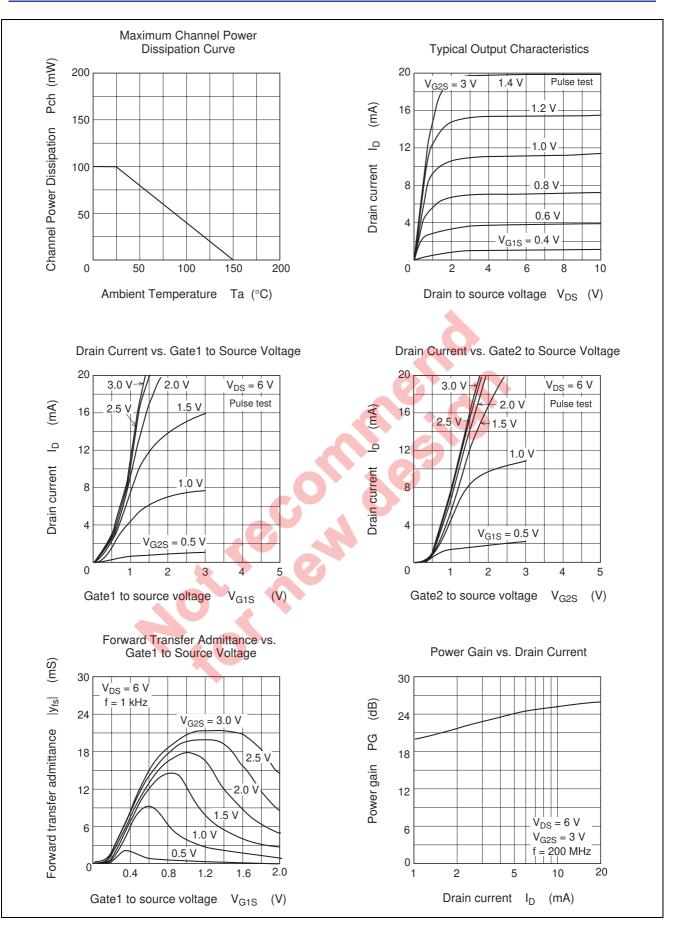
			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	12	V
Gate 1 to source voltage	V <sub>G1S</sub>	±8	V
Gate 2 to source voltage	V <sub>G2S</sub>	±8	V
Drain current	ID	25	mA
Channel power dissipation	Pch	100	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	۵°

# **Electrical Characteristics**

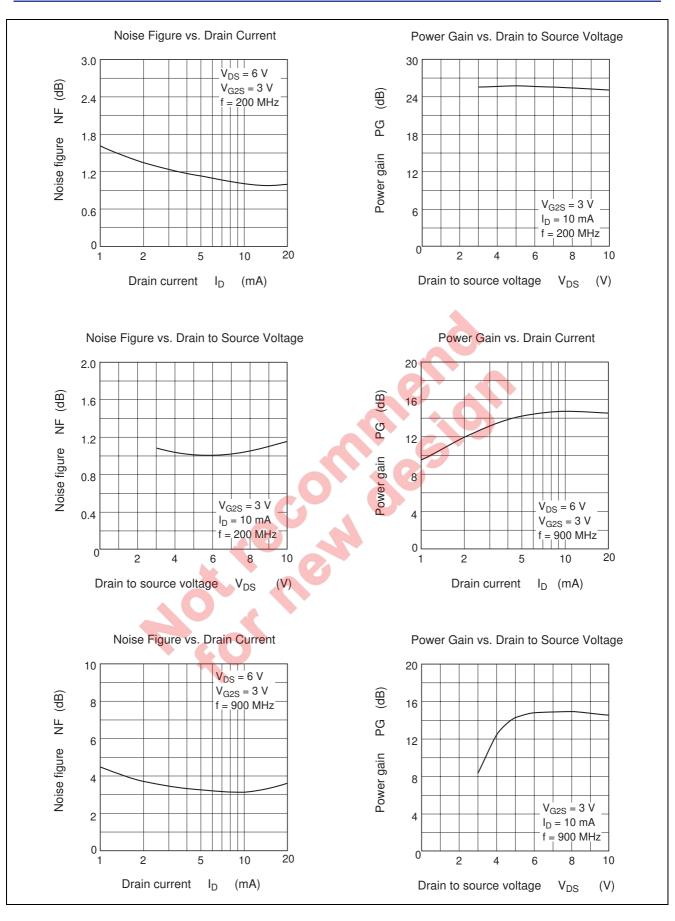
			-			$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Мах	Unit	Test conditions	
Drain to source breakdown voltage	V <sub>(BR)DSX</sub>	12	—	—	V	$I_D$ = 200 $\mu$ A , $V_{G1S}$ = $-3$ V,	
						V <sub>G2S</sub> = -3 V	
Gate 1 to source breakdown voltage	V <sub>(BR)G1SS</sub>	±8	—	_	V	$I_{G1} = \pm 10 \ \mu A$ , $V_{G2S} = V_{DS} = 0$	
Gate 2 to source breakdown voltage	$V_{(BR) G2SS}$	±8	—	—	V	$I_{G2}$ = ±10 µA, $V_{G1S}$ = $V_{DS}$ = 0	
Gate 1 cutoff current	I <sub>G1SS</sub>		—	±100	nA	$V_{G1S}$ = ±6 V, $V_{G2S}$ = $V_{DS}$ = 0	
Gate 2 cutoff current	I <sub>G2SS</sub>	_	—	±100	nA	$V_{G2S} = \pm 6 V, V_{G1S} = V_{DS} = 0$	
Drain current	I <sub>DS(on)</sub>	0.5	_	10	mA	V <sub>DS</sub> = 6 V, V <sub>G1S</sub> = 0.75 V,	
						V <sub>G2S</sub> = 3 V	
Gate 1 to source cutoff voltage	V <sub>G1S(off)</sub>	0		+1.0	V	$V_{DS} = 10 \text{ V}, \text{ V}_{G2S} = 3 \text{ V},$	
						I <sub>D</sub> = 100 μA	
Gate 2 to source cutoff voltage	V <sub>G2S(off)</sub>	0		+1.0	V	V <sub>DS</sub> = 10 V, V <sub>G1S</sub> = 3 V,	
						I <sub>D</sub> = 100 μA	
Forward transfer admittance	y <sub>fs</sub>	16	20	_	mS	$V_{DS} = 6 V, V_{G2S} = 3 V,$	
						I <sub>D</sub> = 10 mA, f = 1 kHz	
Input capacitance	Ciss	2.4	2.9	3.4	pF	$V_{DS} = 6 V, V_{G2S} = 3 V,$	
Output capacitance	Coss	0.8	1.0	1.4	pF	I <sub>D</sub> = 10 mA, f = 1 MHz	
Reverse transfer capacitance	Crss		0.023	0.04	pF		
Power gain	PG	22	25	_	dB	$V_{DS} = 6 V, V_{G2S} = 3 V,$	
Noise figure	NF	_	1.0	1.8	dB	I <sub>D</sub> = 10 mA, f = 200 MHz	
Power gain	PG	12	15	—	dB	V <sub>DS</sub> = 6 V, V <sub>G2S</sub> = 3 V,	
Noise figure	NF	_	3.2	4.5	dB	I <sub>D</sub> = 10 mA, f = 900 MHz	
Noise figure	NF	_	2.8	3.5	dB	$V_{DS} = 6 V, V_{G2S} = 3 V,$	
						I <sub>D</sub> = 10 mA, f = 60 MHz	

 $(Ta = 25^{\circ}C)$ 

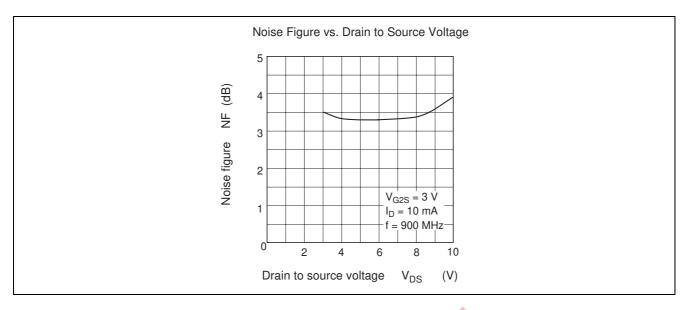
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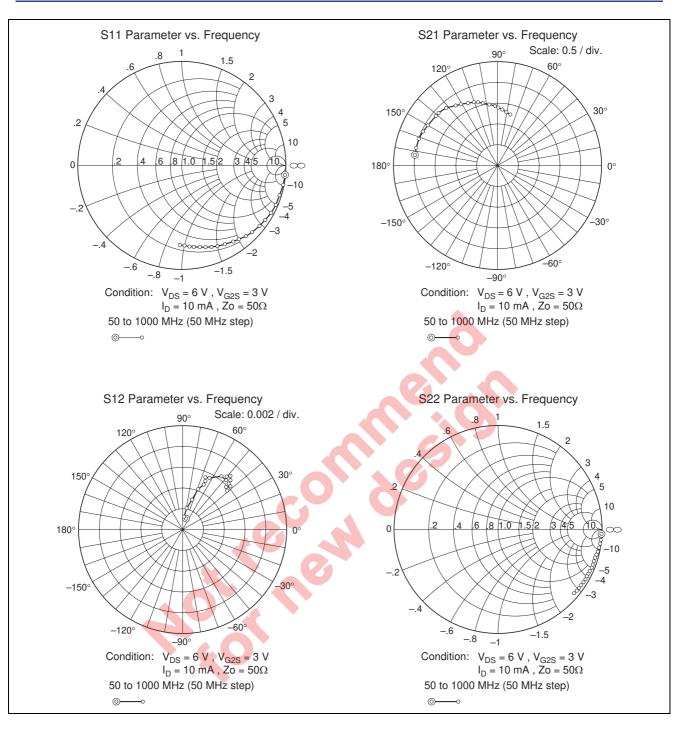














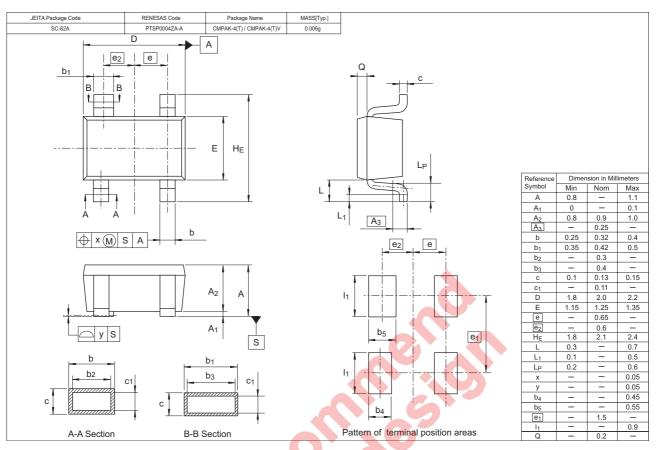
### **S** Parameter

$(V_{DS} = 6 V)$	$V_{G2S} = 3$	$V, I_D = 10$	$mA, Z_0 = 50 \Omega$
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Freq.		S11		S21		S12		S22	
(MHz)	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	
50	0.994	-5.8	2.04	173.6	0.00116	76.9	0.993	-2.2	
100	0.993	-11.0	2.02	167.4	0.00132	85.7	0.993	-4.5	
150	0.986	-16.8	2.00	161.5	0.00229	78.2	0.991	-6.4	
200	0.980	-22.5	1.98	155.5	0.00313	73.5	0.990	-8.5	
250	0.973	-27.8	1.94	149.6	0.00427	68.7	0.987	-10.5	
300	0.950	-33.0	1.90	142.6	0.00473	63.9	0.985	-12.5	
350	0.936	-38.3	1.86	137.1	0.00536	64.3	0.982	-14.4	
400	0.924	-43.4	1.83	131.6	0.00561	64.5	0.979	-16.2	
450	0.912	-48.0	1.77	126.8	0.00562	60.9	0.975	-18.2	
500	0.893	-52.5	1.71	121.0	0.00640	53.5	0.971	-20.2	
550	0.874	-57.3	1.67	115.5	0.00638	49.3	0.967	-22.0	
600	0.859	-62.0	1.64	111.1	0.00647	49.0	0.964	-23.9	
650	0.846	-66.1	1.58	106.7	0.00667	50.2	0.960	-25.8	
700	0.829	-69.8	1.50	102.1	0.00694	49.3	0.955	-27.6	
750	0.810	-74.2	1.46	97.1	0.00661	46.6	0.952	-29.4	
800	0.802	-78.0	1.44	92.7	0.00618	43.7	0.948	-31.2	
850	0.791	-81.6	1.38	88.9	0.00622	44.7	0.944	-33.2	
900	0.778	-84.6	1.34	84.2	0.00615	43.6	0.940	-35.1	
950	0.756	-88.5	1.30	80.2	0.00576	45.1	0.935	-36.8	
1000	0.751	-92.2	1.26	75.9	0.00562	40.7	0.932	-38.5	



## **Package Dimensions**



### **Ordering Information**

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Part Name	Quantity		Shipping Container
3SK298ZP-TL-E	3000 🔪 🚺	¢	178 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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